Mathematical Modeling of Solar PV Panels

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Abstract—Both research and technological development in the area of renewable energy sources are necessary to account for the increase in energy demand and environment problems in the world. Stand-alone photovoltaic systems are the best solutions such as communication system, water pumping and low power appliances in rural area. Such systems are consisting of a PV generator, energy storage devices, AC or DC consumers and elements for power conditions. PV module represents the fundamental power conversion unit of a PV generator system. The output characteristic of PV module depending on the irradiance intensity and the cell’s temperature is nonlinear, so it is necessary to model it for the simulation of maximum power point tracking for stand-alone PV systems. One-diode equivalent circuit is employed to investigate I-V and P-V characteristics of a typical solar module.

Keywords—Solar PV; Modeling; MATLAB; SIMULINK

I. INTRODUCTION

Among the renewable energy resources, the energy due to the photovoltaic (PV) effect can be considered the most essential and prerequisite sustainable resource because of the ubiquity, abundance, and sustainability of solar radiant energy. Regardless of the intermittency of sunlight, solar energy is widely available and is free. Recently, photovoltaic system is recognized to be in the forefront in renewable electric power generation. It can generate direct current electricity without environmental impact and contamination when exposed to solar radiation. Being a semiconductor device, the PV system is static, quiet, free of moving parts, and has little operation and maintenance costs. PV module represents the fundamental power conversion unit of a PV generator system. The output characteristics of a PV module depend on the solar insolation, the cell temperature and the output voltage of the PV module. Since PV module has nonlinear characteristics, it is necessary to model it for the design and simulation of maximum power point tracking (MPPT) for PV system applications. Mathematical modeling of PV module is being continuously updated to enable researcher to have a better understanding of its working. [1]-[6]

II. MODELLING OF PHOTOVOLTAIC SYSTEM

A. Modelling of PV Module:

The model does not take into account the internal losses of the current. A diode is connected in-parallel with the light generated current source (Fig. 1a). The output current I is obtained by Kirchhoff law:

\[ I = I_{ph} + I_d \]

(1)

\( I_{ph} \) is the photocurrent, \( I_d \) is the diode current which is proportional to the saturation current and is given by the equation

\[ I_d = I_0 \left[ \exp \left( \frac{V}{A_N V_T} \right) - 1 \right] \text{ and} \]

(2)

\[ V_T = k T_C / q \]

(3)

\( I_0 \) is the reverse saturation or leakage current of the diode (A), \( V_T = 26 \text{ mV at 300 K for silicium cell, T_c is the actual cell temperature (K), k Boltzmann constant 1.381} \times 10^{-23} J/K, q \text{ electron charge (1.602} \times 10^{-19} C). V_T \text{ is called the thermal voltage because of its exclusive dependence of temperature.}

Ns: is the number of PV cells connected in series. A is the ideality factor. It depends on PV cell technology and can be chosen in Table 1. It is necessary to underline that A is a constant which depends on PV cell technology. All the terms by which, V is divided in equation (2) under exponential function are inversely proportional to cell temperature and so, vary with varying conditions. In this work, this term is designed by ‘a’ and called the thermal voltage (V), the ideality factor, is considered constant and is chosen in Table 1 according to technology of the PV cell. The thermal voltage “a” is presented by the below equation [1].
\[ I_0 = I_{ph,ref} - I_{0,ref} \left[ \exp \left( \frac{V}{a \cdot \alpha_{ref}} \right) - 1 \right] \]

(13)

\[ I_{pn,ref} = I_{ph,ref} - I_{0,ref} \left[ \exp \left( \frac{V_{oc,ref}}{a \cdot \alpha_{ref}} \right) - 1 \right] \]

(14)

The (-1) term has to be neglected because it is very smaller than the exponential term. According to equation (11), and by substituting \((I_{pn,ref})\) in equation (14):

\[ 0 \approx I_{sc,ref} - I_{0,ref} \left[ \exp \left( \frac{V_{oc,ref}}{a \cdot \alpha_{ref}} \right) - 1 \right] \]

(15)

So

\[ I_{0,ref} = I_{sc,ref} \left[ \exp \left( \frac{V_{oc,ref}}{a \cdot \alpha_{ref}} \right) - 1 \right] \]

(16)

The reverse saturation current is defined by:

\[ I_0 = \frac{D \cdot T_c}{A \cdot K} \]

(17)

where \( E_G \): Material band gap energy (eV), (1.12 eV for Si).

D= diode diffusion factor.

In order to eliminate the diode diffusion factor, equation (18) is computed twice; at \( T_c \) and at \( T_{c,ref} \). Then, the ratio of the two equations is written in the next expression:

\[ I_0 = I_{0,ref} \left( \frac{T_c}{T_{c,ref}} \right)^3 \exp \left[ \frac{E_G}{A \cdot K} \left( \frac{1}{T_{c,ref}} - \frac{1}{T_c} \right) \right] \]

(18)

\[ I_0 = I_{sc,ref} \exp \left[ \frac{E_G}{A \cdot K} \right] \left( \frac{T_c}{T_{c,ref}} \right)^3 \times \]

(19)

\[ \exp \left[ \frac{E_G}{A \cdot K} \right] \]

\[ \frac{1}{T_{c,ref}} - \frac{1}{T_c} \]

D. Determination of \((R_P \text{ and } R_S)\):

In order to make the proposed model more credible, \( R_P \) and \( R_S \) are chosen so that the computed max power \( P_{mp,ex} \) is equal to the experimental one \( P_{mp,ex} \) at STC conditions. So it is possible to write the next equation

\[ I_{mp,ref} = \frac{P_{mp,ref}}{V_{mp,ref}} = \frac{P_{mp,ex}}{V_{mp,ex}} \]

(20)

The iteration starts at \( R_S = 0 \) which must increase in order to move the modeled Maximum Power Point until it matches with the experimental Maximum Power Point. The corresponding \( R_P \) is then computed. There is only one pair \((R_P,R_S)\) that satisfies this condition. The implementation presented was used to simulate the proposed model by incrementing \( R_S \) until matching \( P_{mp} \) with \( P_{mp,ex} \).[4-6].

**TABLE 1** PWX 500 PV MODULE (49 W) CHARACTERISTICS.

<table>
<thead>
<tr>
<th>Parameters</th>
<th>Values</th>
</tr>
</thead>
<tbody>
<tr>
<td>( P_{mp}(W) )</td>
<td>49</td>
</tr>
<tr>
<td>( I_{mp}(A) )</td>
<td>2.88</td>
</tr>
<tr>
<td>( V_{mp}(V) )</td>
<td>17</td>
</tr>
<tr>
<td>( I_{oc}(A) )</td>
<td>3.11</td>
</tr>
<tr>
<td>( V_{oc}(V) )</td>
<td>21.8</td>
</tr>
<tr>
<td>( R_P(O) )</td>
<td>0.55</td>
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<tr>
<td>( N_{mp} ) (°C)</td>
<td>45</td>
</tr>
<tr>
<td>( I_{sc}(K) )</td>
<td>1.3 * 10^-3</td>
</tr>
<tr>
<td>( R_S(K) )</td>
<td>-72.5 * 10^-3</td>
</tr>
<tr>
<td>( N_S )</td>
<td>36</td>
</tr>
</tbody>
</table>
III. SIMULATION RESULTS
This Part presents the simulation results of mathematical modeling of photovoltaic system. This system has four subsystem, each subsystem defined equations of parameters. The parameters are: $I_{ph}, I_{0,ref}, I_0$ and $I_{pv}$.

A. Model Of the Photovoltaic System in SIMULINK

Based on the equations discussed in previous section, the Simulink block diagrams (Fig 2,3,4 and 5) showing Modeling those equations.

For our convenient, we converted them into a simple block called as subsystem (Fig 6,7,8 and 9).
All blocks are combined to create the final model of PV system. (fig 10)

The whole PV module with 5 units are given in fig 11.

C. The characteristic of the photovoltaic system

The following graphs (Fig 12, 13) show the relationship between voltage and current and the graphs (Fig 14, 15, 16 and 17) show relationship between voltage and power.

The above figure shows relation between voltage and current, when irradiance is varying. As shows in the graph, when the irradiance increase, the current increase, but the value of \( V_p \) is still constant during irradiance change.
The above figure shows relation between voltage and current when temperature is varying. As shows in the graph when the temperature increase, the current approximately constant , but the value of $V_p$ is still change during temperature changes.

The above figure shows relation between voltage and power when irradiance is varying. As shows in the graph when the irradiance increase, the power increase, but the value of $V_p$ is still constant during irradiance change. The below figures show relation between voltage and current (V-I) and voltage and power (V-P) when the series resistance(Rs) is varying. As shows in the graph when the series resistance Rs increase the current and power decrease. Further more, when Rs decrease the peak of power move to the right and the V-I characteristic become more rectangular form .However, the value of Rs is given by manufacturer.

IV CONCLUSION

The presented work is a detailed modeling and simulation of the PV cell and module. It is implemented under MATLAB/ Simulink environment; the most used software by researchers and engineers. This model is first drafted in accordance with the fundamentals of semiconductors and the PV cell technology. In other words, the PV module parameters have been selected according to their variation with illumination and temperature. It means that for any type of PV module, one can use this model and determine all the necessary parameters under any new conditions of irradiance and temperature and then, obtain the I(V) and P(V) characteristics. This model can be considered as a tool which can be used to study all types of PV modules available in markets, especially, their behavior under different weather data of standard test conditions (STC). It is important to compute $R_s$, even if it is given by a manufacturer because the experimental Maximum Power Point does not match with the computed one. For each iteration, a pair of $(R_s, R_p)$ is obtained. But only one pair satisfies the condition of matching the modeled and the experimental peak power. So, $R_s$ is iteratively increased until satisfying the condition. The proposed $R_p$ model gave $(R_s = 0.45 \Omega, \ R_p = 310.0248 \Omega)$ instead of $(R_s = 0.55 \Omega, \ R_p \ not \ provided)$. So it can be estimated to be more accurate in simulating the PV module. The proposed procedure provides an accurate, reliable and easy-to-tune model of photovoltaic array. Furthermore, it also robust advantageous in investigating the solar PV array operation from different physical parameters (series, shunt resistance, ideality factor, etc.) and working condition (varying temperature, irradiation and especially partial shadow effect) aspects.
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REFERENCES


